

# New Family of Liquid and Solid Guanidine-based *n*-Type Dopants for Solution-Processed Perovskite Solar Cells

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## Abstract

We present a series of new dopants based on a bicyclic guanidine-type structure, 1,5,7-triazabicyclo[4.4.0]dec-5-ene (TBD), for organic semiconductors. A series of TBD derivatives that were alkylated at the 7-position were synthesized and their physical properties were determined. These stable dopants were shown to be effective *n*-type dopants for [6,6]-phenyl-C<sub>61</sub>-butyric acid methyl ester (PC<sub>61</sub>BM), poly{[N,N'-bis(2-octyldodecyl)naphthalene-1,4,5,8-bis(dicarboximide)-2,6-diyl]-alt-5,5'-(2,2'-bithiophene)} (P(NDI2OD-T2)) and 3,9-bis(2-methylene-(3-(1,1-dicyanomethylene)-indanone))-5,5,11,11-tetrakis(4-hexylphenyl)-dithieno[2,3-d':2',3'-d']-s-indaceno[1,2-b:5,6-b']dithiophene (ITIC). Films of PC<sub>61</sub>BM doped with 10 mol% of a dimeric derivative of TBD had electrical conductivities of 0.065 S/cm. The utility of the dopants was further shown by doping electron transport layers of PC<sub>61</sub>BM with 2TBD-C10 for methyl ammonium lead iodide (MAPbI<sub>3</sub>) solar cells leading to improved fill factors and PCEs relative to undoped ETLs.

## Introduction

The use of organic semiconductors in applications, such as solar cells, light-emitting diodes, field-effect transistors, and thermoelectric devices, presents a need for efficient dopants.<sup>1–3</sup> Electrical doping of organic semiconductors is necessary to control their conductivity, fill electronic trap states, and to modify carrier-injection barriers at interfaces by shifting line-up of transport levels. Particularly sought after are *n*-type dopants for transport layers in solar cells and light emitting diodes. While *n*-type dopants with low ionization potentials, e.g. tetrathiafulvalene (TTF),<sup>4,5</sup> can be used with a wide variety of organic semiconductors they are not stable under ambient conditions due to their low oxidation potentials. In addition, the dopant must also be incorporated into the semiconductor uniformly which is particularly important for transport layers in solar cells.

A number of strategies have been used to develop air-stable *n*-type dopants. Latent species have been used by generating the reductive species *in-situ* from a stable precursor, for example the hydride-donor leuco crystal violet (LCV) is generated from the crystal violet salt and benzimidazoline radicals.<sup>6</sup> Other strategies include the use of weak bonds that allow cleavage coupled with electron transfer, e.g. a dimer of the 2,3-dihydro-1H-benzimidazole (2-Cyc-DMBI)<sub>2</sub>,<sup>7</sup> or photoactivation of the electron transfer reaction.<sup>8</sup> Organometallic species have been designed such that they may be stable in their undoped form or leverage the latent dopant strategy.<sup>3,9,10</sup>

Tertiary amines have been explored as *n*-type dopants.<sup>11–14</sup> Tetrakis(dimethylamino)ethylene (TDAE) is a strong reducing agent and has been used to *n*-type dope organic semiconductors or to compensate for *p*-type doping.<sup>15</sup> A drawback of TDAE is its volatility, but appropriate functionalization to increase its mass has led to effective *n*-type doping while still maintaining its

solubility.<sup>16</sup> The electron transfer reactions of cyclic amines such as diazabicyclo(5.3.0)non-5-ene (DBN) and 1,8-diazabicyclo(5.4.0)undec-7-ene (DBU) with C<sub>60</sub> have also been examined.<sup>17,18</sup> DBU was found to react with C<sub>60</sub> by electron transfer to form the radical ions C<sub>60</sub><sup>-</sup> and DBU<sup>+</sup>, followed by formation of a diamagnetic adduct with and optical absorbance in the near infrared region.<sup>17</sup> Recently addition of DBU was found to lead to increases in the electrical conductivity of [6,6]-phenyl-C<sub>61</sub>-butyric acid methyl ester (PC<sub>61</sub>BM), poly{[N,N'-bis(2-octyldodecyl)naphthalene-1,4,5,8-bis(dicarboximide)-2,6-diyl]-alt-5,5'-(2,2'-bithiophene)} (P(NDI2OD-T2)) and 3,9-bis(2-methylene-(3-(1,1-dicyanomethylene)-indanone))-5,5,11,11-tetrakis(4-hexylphenyl)-dithieno[2,3-d:2',3'-d']-s-indaceno[1,2-b:5,6-b']dithiophene (ITIC).<sup>19</sup> Electron spin resonance (ESR) demonstrated the formation of radical species in each case, but the mechanism of doping and whether adducts were formed were not explored. Similarly 1-(*o*-Tolyl) biguanide was found to dope PC<sub>61</sub>BM and used as an electron transport layer in MAPbI<sub>3</sub> solar cells.<sup>20</sup> For many tertiary amines, like DBU, their oxidation potential is such that the electron transfer reaction with many organic semiconductors is not thermodynamically favorable and either close contact of the resulting charge separated species or a subsequent reaction makes the doping process favorable.

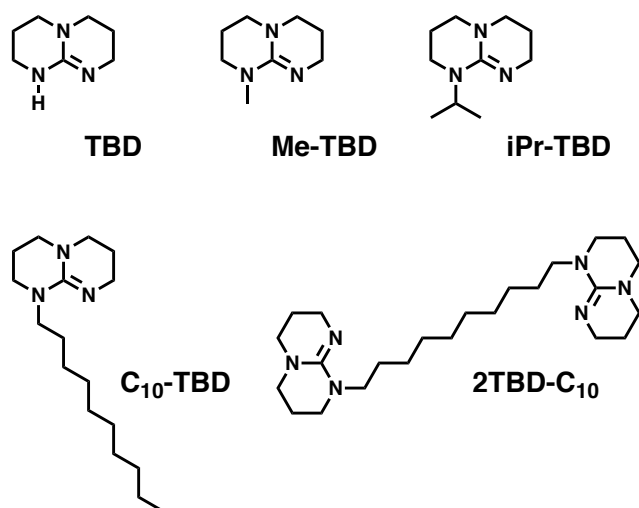
Herein, we present a series of new triazabicyclodecene-based *n*-dopants with varying physical properties, namely **TBD**, ***i*Pr-TBD**, **Me-TBD**, **C10-TBD**, **2TBD-C10** (Figure 1). TBD is a well-known catalyst for transesterification and is considered a superbases.<sup>21,22</sup> We are not aware of its use as a dopant for organic semiconductors. The chemistry of TBD allows for simple substitution at the nitrogen atom in the 7-position allowing for control of its volatility and physical state at room temperature. There have been relatively few reports of a systematic variation of the structure of *n*-type dopants for organic semiconductors.<sup>3,7,23,24</sup> We therefore examined the impact of this

functionalization on the performance as dopants in several organic semiconductors including PC<sub>61</sub>BM, P(NDI2OD-T2) and ITIC. Their utility was further shown by doping electron transport layers of PC<sub>61</sub>BM with **2TBD-C10** in methyl ammonium lead iodide (MAPbI<sub>3</sub>) solar cells leading to improved fill factors and PCEs relative to undoped ETLs.

## Results and Discussion:

### Design and Synthesis of TBD-based dopants

We based our investigation of *n*-type dopants around bicyclic guanidine derivatives (Figure 1). The parent compound is 1,5,7-triazabicyclo[4.4.0]dec-5-ene (**TBD**), which is considered a superbases because of its high Brønsted basicity. The three nitrogen atoms around the central carbon atom provide three equivalent resonance structures, sometimes referred to as Y-aromaticity because of the cross conjugation through a central atom.<sup>25,26</sup> By introducing alkyl substituents on **TBD**, we can alter its physical characteristics and its reactivity, hindering possible side reactions such as nucleophilic substitution with organic semiconductors.



**Figure 1** The chemical structures of *n*-dopants based on 1,5,7-triazabicyclo[4.4.0]dec-5-ene (**TBD**).

7-Methyl-1,5,7-triazabicyclo[4.4.0]dec-5-ene (**Me-TBD**) was commercially available and used without further purification. **TBD** was readily alkylated with primary and secondary alkyl halides by deprotonating with sodium hydride and quenching with the alkyl bromide to yield **iPr-TBD**, **C10-TBD**, and **2TBD-C10**. In contrast, we found that tertiary alkyl halides were not reactive under the conditions used. Details of the synthetic procedure are given in the Supplementary Information and NMR spectra of the compounds are given in Figure S1-S3. **TBD** is a crystalline white solid, but **Me-TBD**, **iPr-TBD**, and **C10-TBD** are oils, with **iPr-TBD** being by far the most viscous. **2TBD-C10** is a white powdery solid likely due to the presence of two TBD units per molecule. All of the derivatives are readily soluble in both polar and non-polar organic solvents, as well as water and methanol. This allows for versatile processing, employing either blends or sequential applications with anti-solvents. As well, this dopant family can be isolated and purified in non-anhydrous solvents and stored in air.

The structure of **TBD** bearing three external nitrogen atoms provides the potential for constructing quaternary ammonium salts via *N*-alkylation of the tertiary amines. As such, our reaction conditions were designed to minimize this possibility by keeping **TBD** in excess relative to the alkyl halide whenever feasible. The reaction of **TBD** with 1,4-dibromobutane was a notable exception that led exclusively to an intramolecular cyclization yielding a **TBD** derivative with a fused 7-membered ring (See Supplementary Information and Figure S4). With shorter chains it appears the proximity of the secondary alkyl bromide to the Schiff base nitrogen facilitates intramolecular cyclization over the reaction with a second equivalent of **TBD**. As the resulting cyclic product with 1,4-dibromobutane is already cationic it was eliminated from our studies.

Our principle motivation behind modifying commercially available TBD was to enhance the stability of the dopant during processing. The volatility of dopants can drastically alter their concentration in thin films after coating and thermal annealing. To this end, we quantified the thermal stability of our dopants through thermal gravimetric analysis (TGA) (Supplementary Information Figure S5). We found that modifying **TBD** with short alkyl chains, especially branched isopropyl, led to much lower initial decomposition temperatures. Longer alkyl chains like decyl, on the other hand, increased the thermal stability. **2TBD-C10**, a solid like **TBD**, but with the added mass of the decyl chain, showed the highest thermal stability, with an initial decomposition temperature around 270° C.

### Electronic Properties.

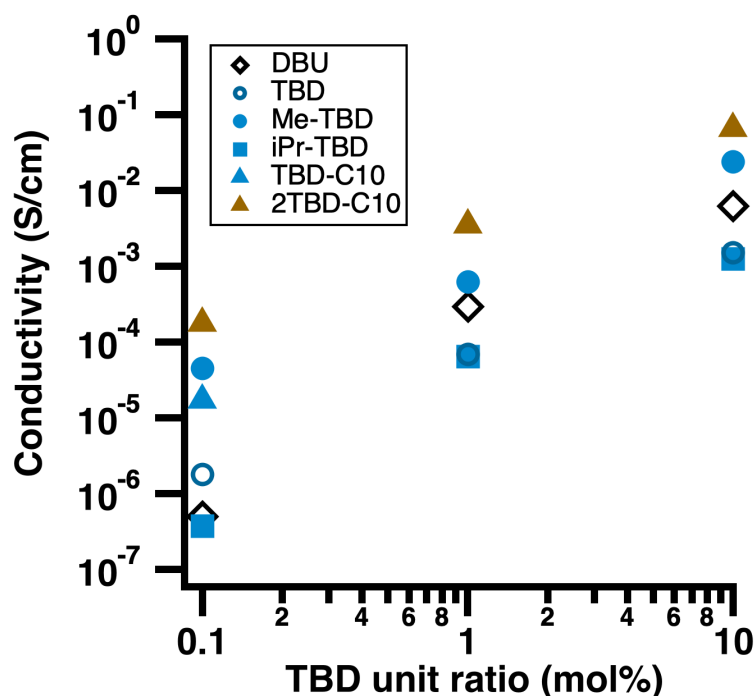
In order to act as efficient *n*-dopants, the **TBD** moiety must be readily oxidized to allow electron transfer to the organic semiconductor. Density functional theory (DFT) calculations show the highest occupied molecular orbital (HOMO) of Me-TBD having contributions from the nitrogen atoms with a node at their central carbon atom as expected (Supplementary Material Figure S6). We expect the series to behave similarly due to the simple alkyl substitution and used cyclic voltammetry (CV) to compare the oxidation potentials of **C10-TBD** and **2TBD-C10** (Supplementary Material Figure S7). Both dopants showed highly irreversible oxidation potentials near  $\approx 1.0$  V relative to a ferrocene/ferrocenium (Fc/Fc<sup>+</sup>) reference. This close match suggests that the two tethered TBD moieties in **2TBD-C10** behave independently. The oxidation potential from CV represents an ionization energy (HOMO level) of about 5.1 eV for both dopants that is intermediate between other comparable tertiary amine dopants. TDAE is a strong reducing agent with an oxidation potential of  $\approx -1$  V vs. Fc/Fc<sup>+</sup>.<sup>27,28</sup> The oxidation potential of DBU has not been

reported in studies of its use as a dopant.<sup>19</sup> We used DFT to calculate the difference in gas-phase ionization energy between TBD-Me and DBU and find that TBD-Me is 0.45 eV easier to ionize. The TBD series should therefore provide improved stability in ambient relative to TDAE and a higher driving force for electron transfer than DBU.

### **n-type Doping of Organic Semiconductors**

We compared the performance of the new TBD-based dopants to DBU as a dopant for PC<sub>61</sub>BM. PC<sub>61</sub>BM is a key material other as a component in organic solar cells<sup>29</sup> and as an electron transport layers in other applications.<sup>15</sup> The in-plane electrical conductivities of doped PC<sub>61</sub>BM films indicate that **2TBD-C10** gives the best conductivity of the series of dopants and gives higher performance than DBU (Figure 2 and Supplementary Information Table S1). The dopants were added over a range of doping ratios, 0.1 to 10 mol% and a super-linear relationship was found between the electrical conductivity and doping ratio (Figure 2). The data fits well to a simple power law ( $y = y_0 + Ax^\alpha$ ) with  $\alpha$  of  $\approx 1.3$ ; super-linear behavior is a common feature of hopping conduction in molecular semiconductors.<sup>30</sup> It is notable that the electrical conductivity of PC<sub>61</sub>BM films doped with **2TBD-C10** ( $6.5 \times 10^{-2}$  S/cm) is as high as that of films doped with (2-Cyc-DMBI)<sub>2</sub>: the maximum conductivity of (2-Cyc-DMBI)<sub>2</sub> doped PC<sub>61</sub>BM films is reported to be  $4.7 \times 10^{-3}$  S/cm at 10 mol% addition.<sup>7</sup> If each dopant led to the formation of 1 charge carrier, then the electron mobility can be estimated as  $\approx 4 \times 10^{-3}$  cm<sup>2</sup>V<sup>-1</sup>s<sup>-1</sup> at 10 mol% and  $\approx 1 \times 10^{-2}$  cm<sup>2</sup>V<sup>-1</sup>s<sup>-1</sup> at 1 mol% based on a mass density of PC<sub>61</sub>BM of  $\approx 1.5$  g cm<sup>-3</sup>. These values are comparable to mobilities of  $\approx 4 \times 10^{-2}$  cm<sup>2</sup>V<sup>-1</sup>s<sup>-1</sup> extracted from the current-voltage characteristics of thin film transistors of PC<sub>61</sub>BM doped with  $\sim 1$  mol% of N-DMBI.<sup>31</sup> While it is difficult to quantitatively extract the efficiency of doping, it must be relatively high otherwise the carrier mobility would need to be

larger than typically observed to account for the electrical conductivity. The effectiveness of **2TBD-C10** as a dopant can partly be explained by its good miscibility with PC<sub>61</sub>BM. The AFM topography images of doped PC<sub>61</sub>BM films show no aggregation or phase separation for each concentration and look similar to that of a pristine PCBM film (Supplementary Information Figure S8).



**Figure 2.** Electrical conductivities of films of PC<sub>61</sub>BM doped with TBD-derivatives and DBU as a function of the molar ratio. **TBD-C10** has a data point only at 0.1 mol% because films could not be cast at higher molar ratios

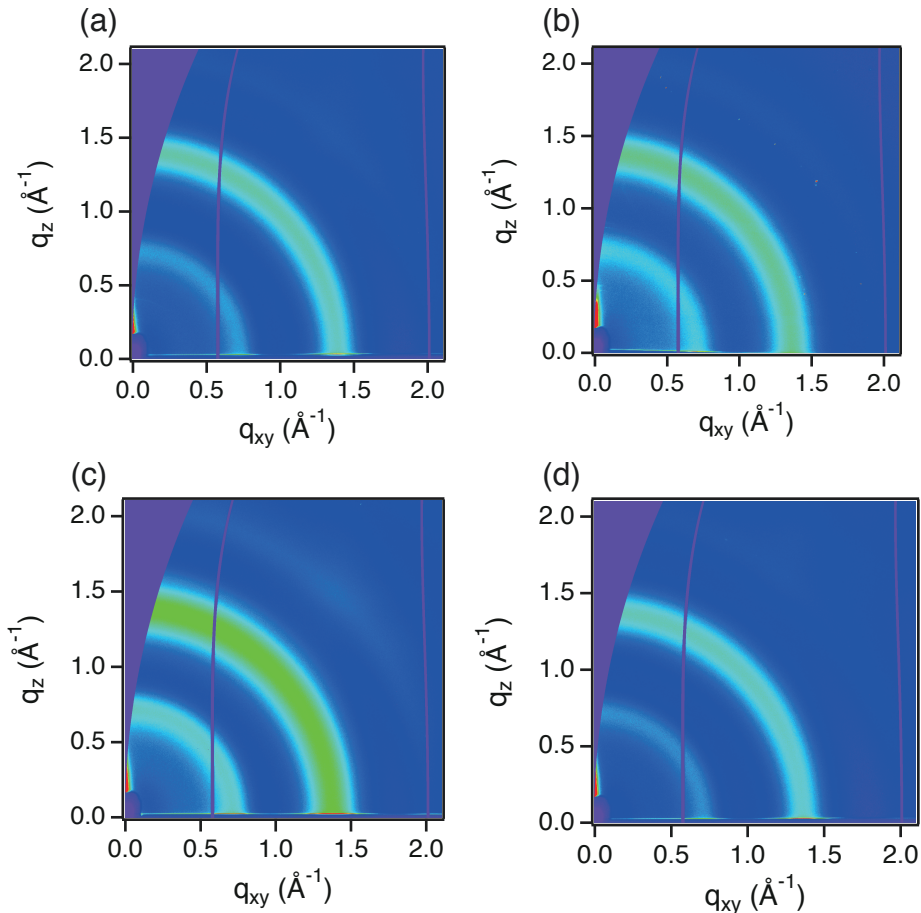
We find that the alkylation of the 7- position of **TBD** affects both the electrical conductivity and processability of doped films of PC<sub>61</sub>BM. The branched isopropyl derivative, **iPr-TBD**, gave similar electrical conductivities as **TBD** suggesting that the alkylation itself is not the sole origin of the increase. The addition of relatively long linear alkyl groups, i.e. **TBD-C10**, led difficulties



in casting doped films at high molar ratios due to dewetting of the films from the substrate. We attribute this issue to the surfactant-like nature of its structure of **TBD-C10**. This issue was eliminated by using the dimer, **2TBD-C10**, which was processable at all concentration used.

PC<sub>61</sub>BM films doped by **2TBD-C10** are more tolerant to thermal annealing than those by TBDs with short side chains. The conductivity of 1 mol% **2TBD-C10** doped PCBM film increased from  $3.5 \times 10^{-3}$  to  $7.4 \times 10^{-3}$  S/cm after thermal annealing on a hot plate in nitrogen at 150 °C for 30 min, whereas that of **Me-TBD** doped one dropped from  $6.2 \times 10^{-4}$  to  $5.6 \times 10^{-5}$  S/cm in the same treatment. This change is well-correlated to the TGA data for the dopants that showed a higher compositions temperature for longer chain derivatives. The improved processability of **2BD-C10** and its higher thermal tolerance led us to focus on this dopant relative to others in the series.

We measured grazing incident wide angle X-ray scattering (GIWAXS) to determine if there were signs of aggregation or changes in the structural order of doped PC<sub>61</sub>BM thin films. The scattering patterns of PC<sub>61</sub>BM films without dopant and with 10 mol% of **2TBD-C10**, **Me-TBD**, and **iPr-TBD** are almost identical (Figure 3 and Supplementary Information Figure S9). They have two rings at around  $q = 0.7$  and  $1.4 \text{ \AA}^{-1}$  with full width at half maximum (FWHM) of about 0.20 and  $0.15 \text{ \AA}^{-1}$ , respectively, indicating those films are amorphous as typically seen in fullerene films. We found that the peaks shift slightly toward lower  $q$  range by  $\approx 0.03 \text{ \AA}^{-1}$  upon doping, which is a small shift given the FWHM of the peaks. Importantly, we do not observe any new peaks upon doping with **2TBD-C10**, a solid dopant suggesting that there are no aggregates of the dopant and likely molecularly mixing of the compound with PC<sub>61</sub>BM. If an adduct is formed between the dopant and PC<sub>61</sub>BM, it does not strongly perturb the film.



**Figure 3.** 2-Dimensional GIWAXS images of (a) pristine PC<sub>61</sub>BM, (b) PC<sub>61</sub>BM with 10 mol% **2TBD-C10**, (c) PC<sub>61</sub>BM with 10 mol% **Me-TBD**, and (d) PC<sub>61</sub>BM with 10 mol% **iPr-TBD**. of undoped and doped PC<sub>61</sub>BM films.

We found that addition of **2TBD-C10** leads to *n*-type doping of organic semiconductors beyond PC<sub>61</sub>BM. We examined the doping of P(NDI2OD-T2), a well-studied naphthalenediimide based conjugated polymer, because it has been broadly used as a test case for *n*-type doping and it has an electron affinity near that of PC<sub>61</sub>BM.<sup>7,9,19,24,28</sup> Thin films of P(NDI2OD-T2) doped with **2TBD-C10** at 10 mol% have an electrical conductivity of  $7.0 \times 10^{-4}$  S/cm (Table 1). This value is comparable to value using (2-Cyc-DMBI)<sub>2</sub> ( $2.8 \times 10^{-3}$  S/cm with 11 mol%)<sup>7</sup> and N-DMBI ( $8 \times 10^{-4}$  S/cm with 10 mol%)<sup>24</sup> as dopants. In contrast, **TBD-C10** gives three orders of magnitude

lower conductivity ( $1.5 \times 10^{-7}$  S/cm) in 10 mol% doping, indicating that the dimer is significantly more effective. **2TBD-C10** also dopes ITIC, an acceptor–donor–acceptor shape non-fullerene acceptor for organic photovoltaics, yielding conductivities of  $4.3 \times 10^{-6}$  and  $1.7 \times 10^{-6}$  S/cm with 10 and 1 mol% doping, respectively. These relatively low conductivities are partly due to lower electron mobility in ITIC ( $\sim 10^{-2}$  cm<sup>2</sup>/Vs) than that of PC<sub>61</sub>BM ( $\sim 10^{-1}$  cm<sup>2</sup>/Vs) based on measurements of field-effect transistors.<sup>32</sup>

**Table 1.** Electrical conductivities (S/cm) of thin films of organic semiconductors as a function of concentration of the TBD dopant.

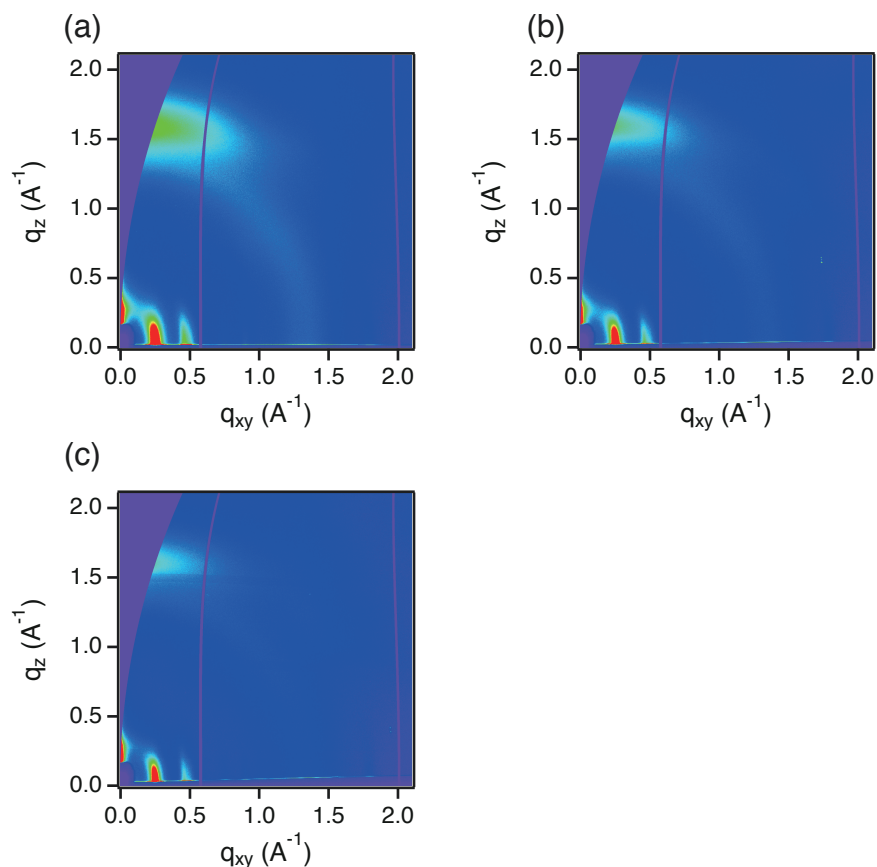
dopant	2TBD-C10	2TBD-C10	2TBD-C10	TBD-C10
concentration	10 mol%	1 mol%	0.1 mol%	10 mol%
PC <sub>61</sub> BM	$6.5 \times 10^{-2}$	$3.5 \times 10^{-3}$	$1.8 \times 10^{-4}$	nd**
P(NDI2OD-2T)	$7.0 \times 10^{-4}$	$2.4 \times 10^{-6}$	nd*	$1.5 \times 10^{-7}$
ITIC	$4.3 \times 10^{-6}$	$1.7 \times 10^{-6}$	nd*	nd**

\*Too low to measure

\*\*The films were not obtained due to dewetting.

The scattering patterns of P(NDI2OD-T2) are also insensitive to doping with **2TBD-C10** and **TBD-C10** (Figure 4 and Supplementary Information Figure S10). The scattering pattern of pristine P(NDI2OD-T2) show a  $\pi$ -steking feature at  $1.6 \text{ \AA}^{-1}$  in the out-of-plane direction and alkyl stacking features at  $0.25$  and  $0.47 \text{ \AA}^{-1}$  in the in-plane direction, indicating a face-on orientation of its crystalline moieties. Addition of **2TBD-10** or **TBD-C10** does not result in notable shift of the polymer originated peaks or appearance of new peaks. We thus conclude that the crystalline

moieties of the polymer are impenetrable to these TBD dopants, and the dopants reside in the amorphous moieties without forming crystallites. This conclusion is not unique to the TBD dopants but also holds true for conventional dopants such as N-DMBI as we previously reported.<sup>[5]</sup>



**Figure 4.** 2-Dimensional GIWAXS scattering of (a) pristine P(NDI2OD-T2), (b) P(NDI2OD-T2) with 10 mol% **2TBD-C10**, and (c) P(NDI2OD-T2) with 10 mol% **TBD-C10**.

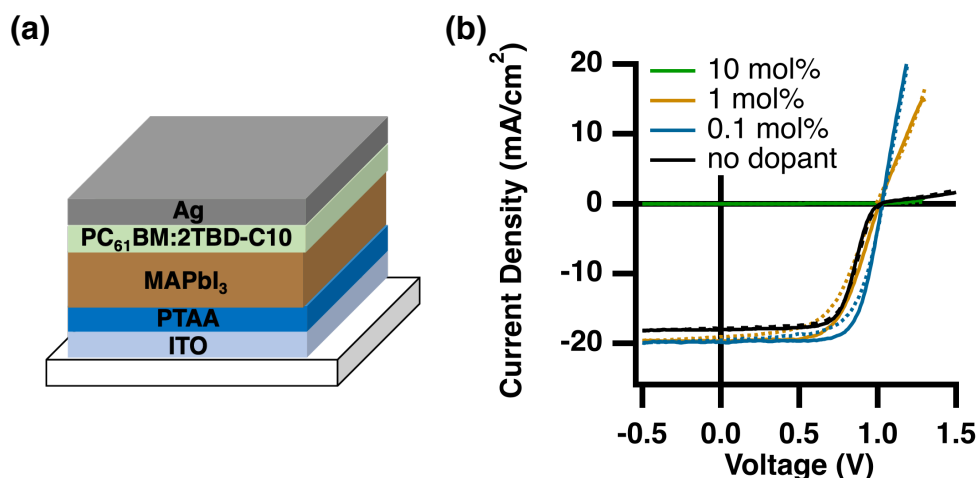
### Doping Electron Transport Layers in Perovskite Solar Cells.

Doping of the hole and electron transport layers in organic metal halide (perovskite) solar cells has proven to be a beneficial strategy for improving their performance.<sup>33–37</sup> Organic amines have been used to improve carrier extraction in organic electron transport layers (ETLs) of perovskite solar cells. Polyethyleneimine (PEIE) has frequently been used as an interlayer to modify the work

function at electrodes by doping or forming interfacial dipole layers.<sup>38,39</sup> Poly[(9,9-bis(3'-(N,N-dimethylamino) propyl)-2,7-fluorene)-alt-2,7-(9,9-dioctylfluorene)] (PFN) has been used as an effective interlayer with PC<sub>61</sub>BM ETLs in perovskite solar cells,<sup>40</sup> with some attributing the improvement due to doping.<sup>37</sup> Co-polymers of PFN and naphthalenediimides as ETLs have also shown to lead to good fill factors in solar cells as well demonstrating the broad utility of aliphatic tertiary amine functionalities.<sup>41</sup> The success of these materials suggested that the TBD-dopants would be compatible with perovskite solar cells.

To demonstrate the utility of the TBD-based dopants, we fabricated solar cells of methylammonium lead triiodide (MAPbI<sub>3</sub>) with an inverted structure, i.e. ETL cast on top of the MAPbI<sub>3</sub> layer. We examined **2TBD-C10** doped PC<sub>61</sub>BM as the ETL to assess the impact of doping on the behavior of the solar cells. The device stack is glass/ITO (20  $\Omega$ /sq)/polytriarylamine (PTAA, ~5 nm)/MAPbI<sub>3</sub> (~400 nm)/ PC<sub>61</sub>BM (~100 nm)/Ag (80 nm). The results clearly show that doping PC<sub>61</sub>BM with **2TBD-C10** works to improve the performance with a clear optimal molar ratio of dopant (**Figure 10**). The devices without doping give a power conversion efficiency (*PCE*) of 11.8% with a kink in the current-voltage (*J-V*) characteristic around the  $V_{OC}$  condition ( $J = 0$  mA/cm<sup>2</sup>). Because the  $J_{SC}$  (18.0 mA/cm<sup>2</sup>) of the solar cell is reasonable given the thickness of the MAPbI<sub>3</sub> layer, the kink is a sign of an electron injection barrier at the Ag/ PC<sub>61</sub>BM interface due to Schottky barrier formation. When the carrier concentration of PC<sub>61</sub>BM is increased with 0.1 mol% of **2TBD-C10**, the kink disappears giving a *PCE* of 14.5% with improved fill-factor (*FF*) of 0.71. Further addition of the dopant, however, leads to deterioration of the device performance. With 1 mol% of doping, *FF* is reduced to 0.61 while retaining the  $V_{OC}$  and  $J_{SC}$ , giving a *PCE* of 12.3%. With 10 mol%, the  $J_{SC}$  is almost entirely quenched and the solar cell has very poor performance. We previously found that increasing the doping of ETLs can lead to composition

of the surface of MAPbI<sub>3</sub> by inducing release of iodine.<sup>42</sup> It is possible that similar degradation happens here in the highly doped devices, increasing the resistance at the MAPbI<sub>3</sub>/PC<sub>61</sub>BM interface and blocking charge extraction from the bulk of the active layer.



**Figure 5.** (a) Schematic of the solar cell structure of glass/ITO (20  $\Omega/\text{sq}$ )/polytriarylamine (PTAA,  $\sim 5$  nm)/MAPbI<sub>3</sub> ( $\sim 400$  nm)/ PC<sub>61</sub>BM:dopant ( $\sim 100$  nm)/Ag (80 nm) (b)  $J$ - $V$  characteristics of MAPbI<sub>3</sub> photovoltaics using PC<sub>61</sub>BM doped with 2TBD-C10 in a ratio of (black) 0 mol%, (blue) 0.1 mol%, (gold) 1 mol% and (green) 10 mol%. Dashed lines represent forward scans, while solid lines reverse scans.

**Table 2.** Device parameters of MAPbI<sub>3</sub> based photovoltaics with the structure: glass/ITO/PTAA/MAPbI<sub>3</sub>/PC<sub>61</sub>BM:2TBD-C10/Ag

2TBD-C10 (mol%)	V <sub>oc</sub> (V)	J <sub>sc</sub> (mA/cm <sup>2</sup> )	FF	PCE (%)
0 (not doped)	1.02 $\pm$ 0.00	18.0 $\pm$ 0.33	0.64 $\pm$ 0.01	11.8 $\pm$ 0.5
0.1	1.02 $\pm$ 0.00	19.8 $\pm$ 0.15	0.70 $\pm$ 0.01	14.4 $\pm$ 0.17
1	1.00 $\pm$ 0.02	19.2 $\pm$ 0.45	0.60 $\pm$ 0.02	11.7 $\pm$ 0.68
10	$\sim 0.2$	$< 0.01$	$\sim 0.2$	$< 0.1$

## Conclusions

In conclusion, we have shown that triazabicyclodecene-based compounds can effectively *n*-dope organic semiconductors, including PC<sub>61</sub>BM. Tethering two **TBD** moieties with a simple alkyl chain gave a solid dopant, **2TBD-C10**, with high thermal stability above 250°C and effective doping of a range of organic semiconductors. PC<sub>61</sub>BM films doped by **2TBD-C10** were the most tolerant to thermal annealing and reached in-plane conductivities of  $6.5 \times 10^{-2}$  S/cm. Furthermore, incorporating **2TBD-C10** doped PC<sub>61</sub>BM as the electron transport layer (ETL) in MAPbI<sub>3</sub> photovoltaics led to a 23% increase in performance, from 11.8% to 14.5% PCE. Although beyond the scope of this report, there may be added benefits of using superbases like the TBD series as *n*-type dopants with perovskite solar cells. The ability of TBD and its conjugate Lewis acid to complex or react with stray metal atoms,<sup>43,44</sup> CO<sub>2</sub>,<sup>45,46</sup> and reactive oxygen species.<sup>47,48</sup>

## Conflicts of Interest

A patent has been filed by the authors on the use of TBD-derivatives as dopants.

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